



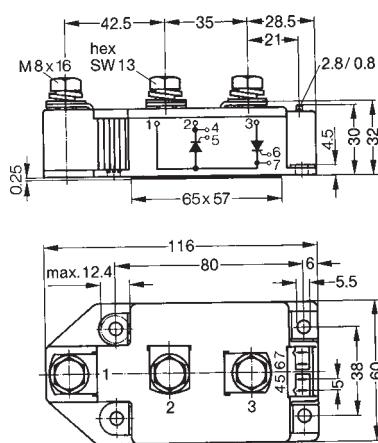
Symbol	Conditions	Characteristic Values	
$I_{RRM}$	$T_{VJ} = T_{VJM}$ ; $V_R = V_{RRM}$ ; $V_D = V_{DRM}$	70	mA
$I_{DRM}$		40	mA
$V_T, V_F$	$I_T/I_F = 600 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$	1.36	V
$V_{T0}$	For power-loss calculations only ( $T_{VJ} = 140^\circ\text{C}$ )	0.85	V
$r_T$		0.82	$\text{m}\Omega$
$V_{GT}$	$V_D = 6 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	2	V
$I_{GT}$	$V_D = 6 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	150	mA
$V_{GD}$	$T_{VJ} = T_{VJM}$ ; $V_D = \frac{2}{3} V_{DRM}$	0.25	V
$I_{GD}$		10	mA
$I_L$	$T_{VJ} = 25^\circ\text{C}$ ; $t_p = 30 \mu\text{s}$ ; $V_D = 6 \text{ V}$ $I_G = 0.45 \text{ A}$ ; $dI_G/dt = 0.45 \text{ A}/\mu\text{s}$	200	mA
$I_H$	$T_{VJ} = 25^\circ\text{C}$ ; $V_D = 6 \text{ V}$ ; $R_{GK} = \infty$	150	mA
$t_{gd}$	$T_{VJ} = 25^\circ\text{C}$ ; $V_D = \frac{1}{2} V_{DRM}$ $I_G = 1 \text{ A}$ ; $dI_G/dt = 1 \text{ A}/\mu\text{s}$	2	$\mu\text{s}$
$t_q$	$T_{VJ} = T_{VJM}$ ; $I_T = 300 \text{ A}$ , $t_p = 200 \mu\text{s}$ ; $-di/dt = 10 \text{ A}/\mu\text{s}$ $V_R = 100 \text{ V}$ ; $dv/dt = 50 \text{ V}/\mu\text{s}$ ; $V_D = \frac{2}{3} V_{DRM}$	typ. 200	$\mu\text{s}$
$Q_s$	$T_{VJ} = 125^\circ\text{C}$ ; $I_T/I_F = 400 \text{ A}$ , $-di/dt = 50 \text{ A}/\mu\text{s}$	760	$\mu\text{C}$
$I_{RM}$		275	A
$R_{thJC}$	per thyristor/diode; DC current	0.129	K/W
	per module	0.0645	K/W
$R_{thJK}$	per thyristor/diode; DC current	0.169	K/W
	per module	0.0845	K/W
$d_s$	Creepage distance on surface	12.7	mm
$d_a$	Strike distance through air	9.6	mm
$a$	Maximum allowable acceleration	50	$\text{m}/\text{s}^2$

## Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red  
Type **ZY 180L** (L = Left for pin pair 4/5) } UL 758, style 1385,  
Type **ZY 180R** (R = right for pin pair 6/7) } CSA class 5851, guide 460-1-1

## Dimensions in mm (1 mm = 0.0394")

## MCC



## MCD

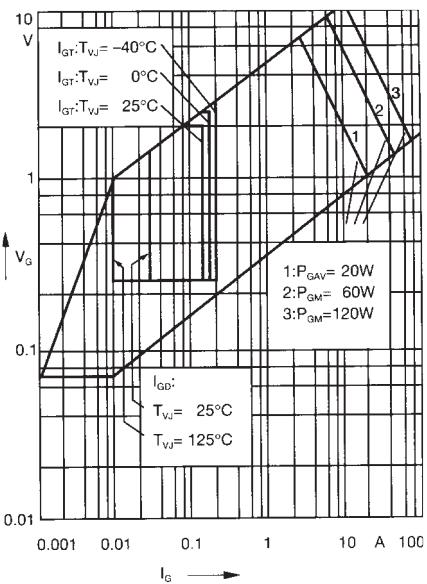
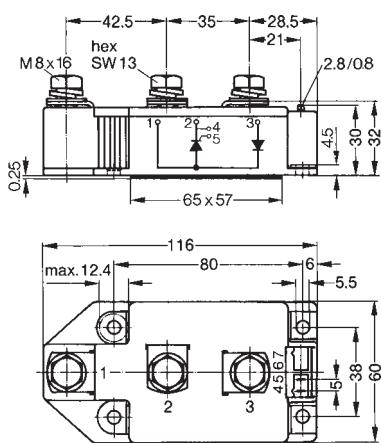


Fig. 1 Gate trigger characteristics

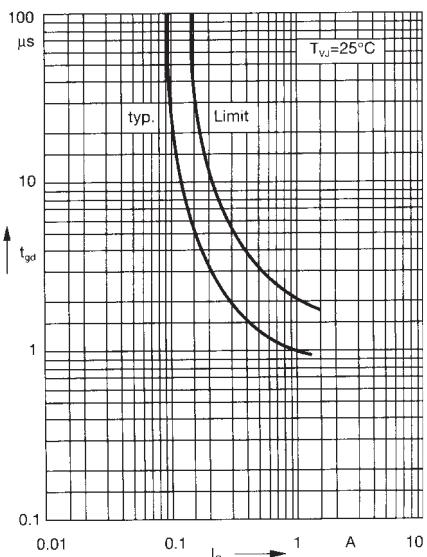
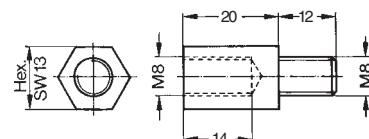


Fig. 2 Gate trigger delay time

Threaded spacer for higher Anode/Cathode construction:

Type **ZY 250**, material brass



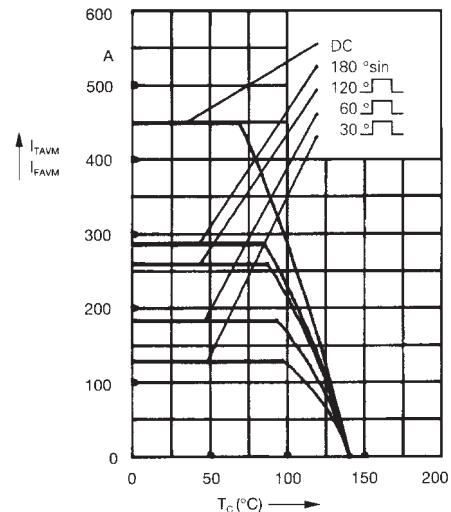
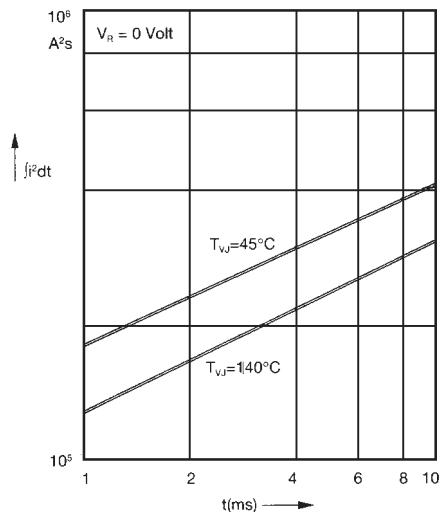
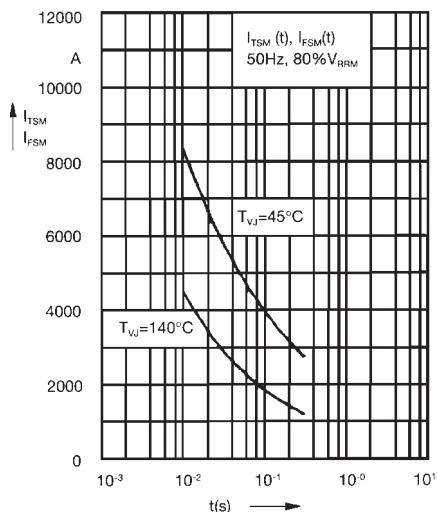
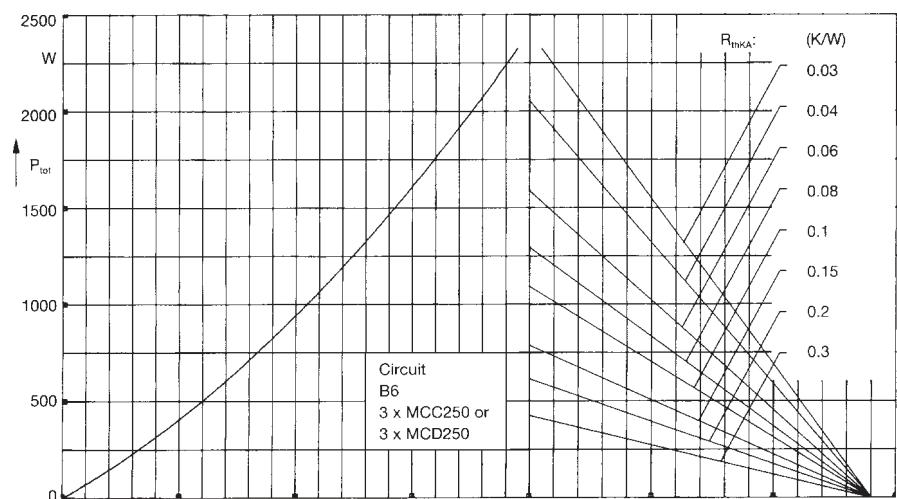
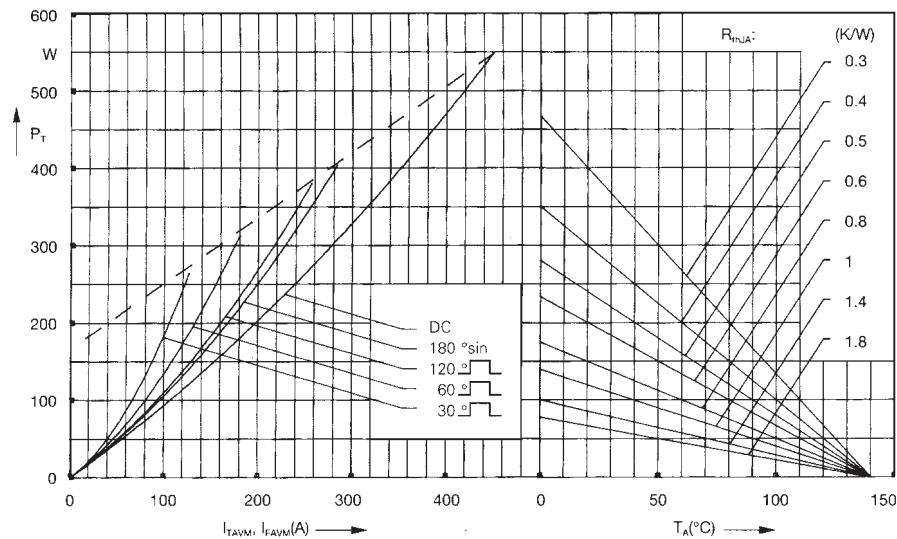
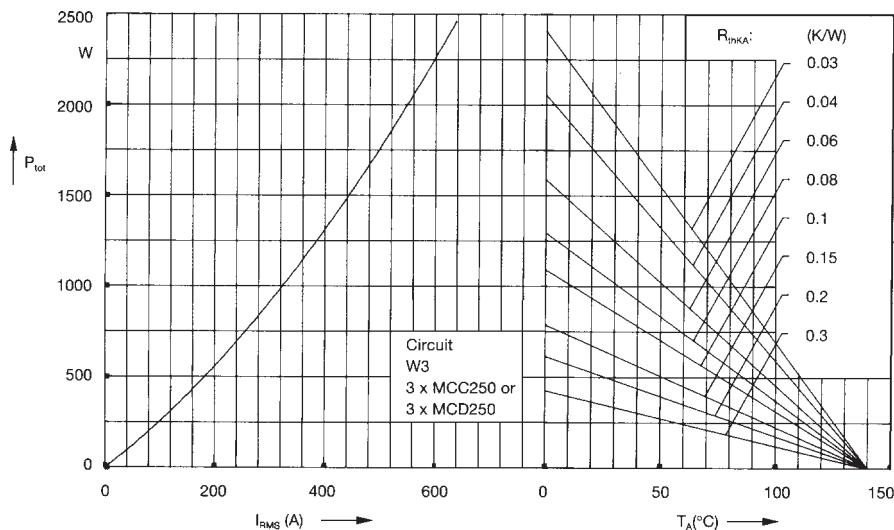


Fig. 3 Surge overload current  
 $I_{TSM}$ ,  $I_{FSM}$ : Crest value,  $t$ : duration

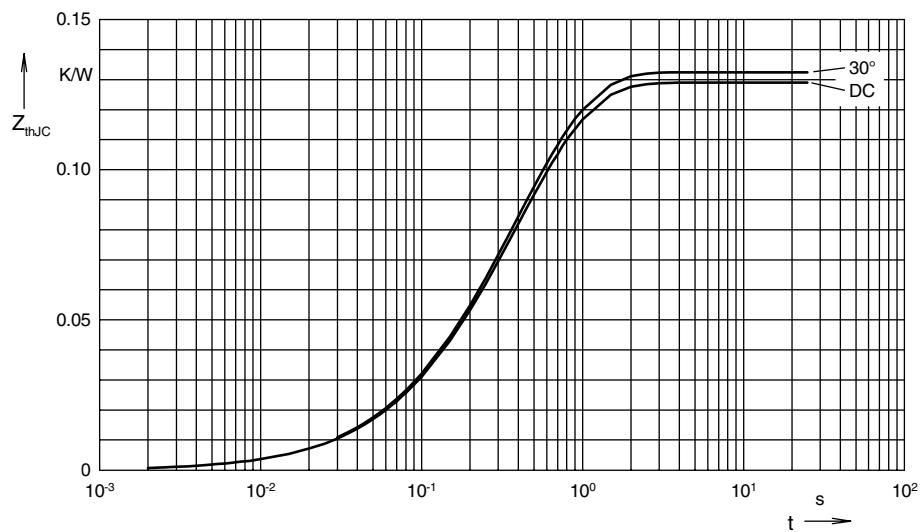
Fig. 4  $j^2dt$  versus time (1-10 ms)

Fig. 4a Maximum forward current at case temperature





**Fig. 7 Three phase AC-controller:  
Power dissipation versus RMS  
output current and ambient  
temperature**



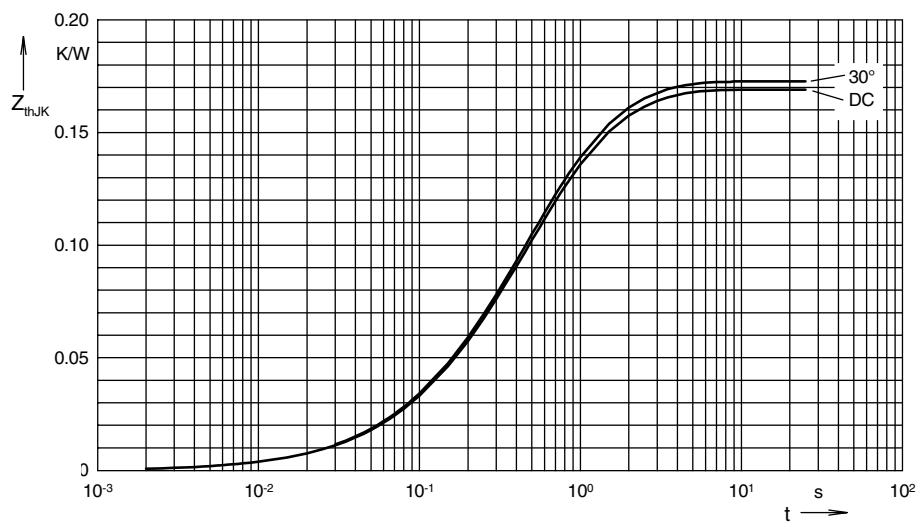
**Fig. 8 Transient thermal impedance  
junction to case (per thyristor or  
diode)**

$R_{thJC}$  for various conduction angles d:

d	$R_{thJC}$ (K/W)
DC	0.129
180°C	0.131
120°C	0.131
60°C	0.132
30°C	0.132

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0035	0.099
2	0.0165	0.168
3	0.1091	0.456



**Fig. 9 Transient thermal impedance  
junction to heatsink (per thyristor or  
diode)**

$R_{thJK}$  for various conduction angles d:

d	$R_{thJK}$ (K/W)
DC	0.169
180°C	0.171
120°C	0.172
60°C	0.172
30°C	0.173

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0033	0.099
2	0.0159	0.168
3	0.1053	0.456
4	0.04	1.36